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FJY3002R NPN Epitaxial Silicon Transistor with Bias Resistor

Description

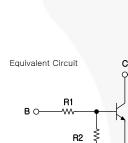
Features

- 100 mA Output Current Capability
- Built-in Bias Resistor ($R_1 = 10 \text{ k}\Omega$, $R_2 = 10 \text{ k}\Omega$)

Application

- Switching, Interface, and Driver Circuits
- Inverters
- Digital Applications in Industrial Segments





nent count and simplifying circuit design.

Transistors with built-in resistors can be excellent

space- and cost-saving solutions by reducing compo-

Ordering Information

Part Number	Top Mark	Package	Packing Method
FJY3002R	S02	SOT-523F 3L	Tape and Reel

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Unit	
V _{CBO}	Collector-Base Voltage	50	V	
V _{CEO}	Collector-Emitter Voltage	50	V	
V _{EBO}	Emitter-Base Voltage	10	V	
۱ _C	Collector Current	100	mA	
Т _Ј	Junction Temperature	150	°C	
T _{STG}	Storage Temperature Range	-55 to 150	°C	

Thermal Characteristics⁽¹⁾

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Value	Unit
р	Power Dissipation	200	mW
PD	Derate Above $T_A = 25^{\circ}C$	1.60	mW/°C
R _{0JA}	Thermal Resistance, Junction to Ambient	625	°C/W

Note:

1. PCB size: FR-4 76 x 114 x 0.6T mm³ (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

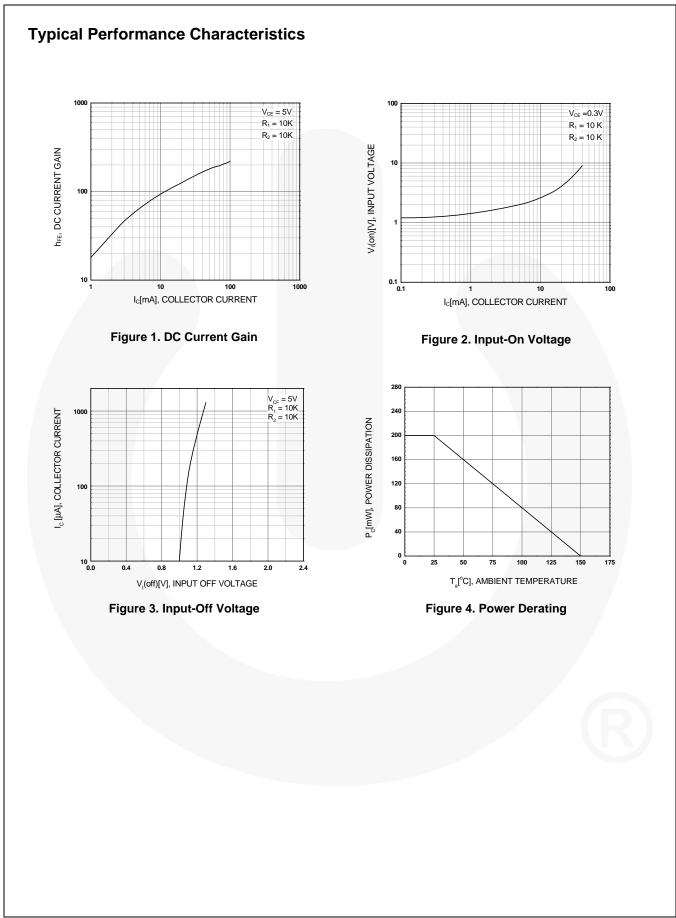
Electrical Characteristics⁽²⁾

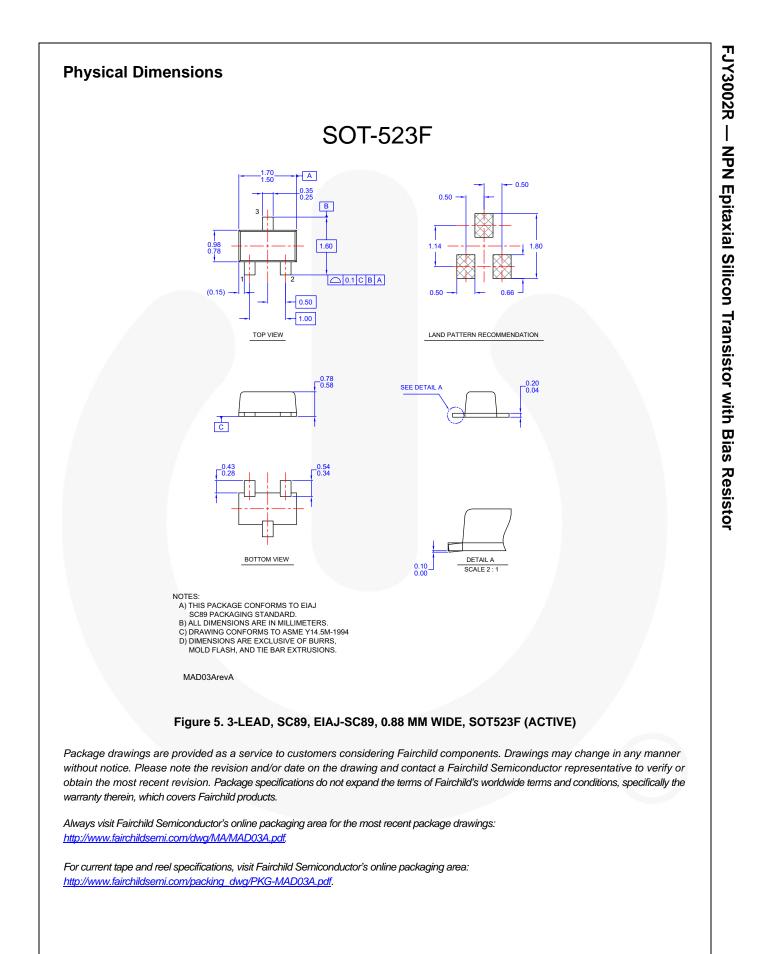
Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V _{(BR)CBO}	Collector-Emitter Breakdown Voltage	$I_{C} = 10 \ \mu A, I_{E} = 0$	50			V
V _{(BR)CEO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu \text{A}, \ I_{\rm B} = 0$	50			V
I _{CBO}	Collector Cut-Off Current	$V_{CB} = 40 \text{ V}, \text{ I}_{E} = 0$			0.1	μΑ
h _{FE}	DC Current Gain	$V_{CE} = 5 \text{ V}, I_{C} = 5 \text{ mA}$	30			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 10 mA, I _B = 0.5 mA			0.3	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 5 \text{ mA}$		250		MHz
C _{cb}	Output Capacitance	$V_{CB} = 10 \text{ V}, I_E = 0,$ f = 1.0 MHz		3.7		pF
V _I (off)	Input-Off Voltage	$V_{CE} = 5 \text{ V}, I_{C} = 100 \mu\text{A}$			0.5	V
V _l (on)	Input-On Voltage	$V_{CE} = 0.3 \text{ V}, I_{C} = 10 \text{ mA}$	3			V
R ₁	Input Resistor		7	10	13	kΩ
R_{1}/R_{2}	Resistor Ratio		0.9	1.0	1.1	

Note:

2. Pulse test: pulse width \leq 300 µs, duty cycle \leq 2%.





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Definition of	Terms
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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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